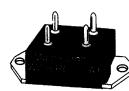


## MINIATURE SOLID STATE RELAY

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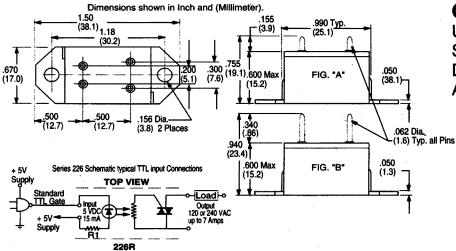
CLASS 226 UP TO 7 AMPS SPST—NO DC INPUTS AC OUTPUTS



COMPATIBLE WITH TTL GATES. PRINTED CIRCUIT AND PUSH-ON TERMINAL PIN VERSIONS.

PUSH-ON TERMINAL RECEPTICALS

FOR 18-22 AWG 02-06-1103 FOR 24-30 02-06-1132 WINCHESTER 156-10185 156-10245



**17.** 

Magnecraft	PUSH ON TERMINALS	FIG "A"	W226R-7-5A1	W226R-7-12A1	W226R-8-5A1	W226R-8-12A1
PART NUMBER	PRINTED CIRCUIT TERMINALS	FIG "B"	W226RE-7-5A1	W226RE-7-12A1	<del>W226R</del> E-8-5A1	W226RE-8-12A1
INPUT CHARACTERISTIC	S					
Input Voltage Range			5VDC	12VDC	5VDC	12VDC
Maximum Pickup Voltage (over operating temperature range)			4.3VDC	10.3VDC	4.3VDC	10.3VDC
Minimum Dropout Voltage (over operating temperature range)			1.5VDC			
Input Current			Input current (at nominal voltage) 13mA typical / 15mA max			
Reverse Polarity Protected			No			
Input Filtered for transients less than one millisecond.			No			
Response Time			Turn on, 16m Sec. Max., Turn off, 60m Sec. Max.		n Sec. Max.	
OUTPUT CHARACTERIS	rics					
Nominal Off State Voltage V <sub>D</sub> (RMS)			120		240	
Maximum Off State Voltage V <sub>D MAX</sub> (RMS)			260		380	
Minimum Off State Voltage V <sub>D MIN</sub> (RMS)			20		40	
Non-Repetitive Peak Voltage V <sub>DSM</sub> (Blocking Voltage)			400		700	
Maximum Rate of Rise of Off State Voltage dv/dt			100V/uSec blocking		4V/uSec commutating	
mounting surface of suitable		ive compo	ound (e.g. <b>silicone</b>	7 <i>A</i> grease between	Amp the SSR mount	ing base and
Minimum Load Current I <sub>T MIN</sub> (RMS) to maintain "On"			20mA			
Non-Repetitive Surge Current I <sub>T SM</sub> (one Cycle Surge)				201	nA	
Tron hopotatro cargo can	rent I <sub>T SM</sub> (one Cycle Surge)			50 A		
Maximum RMS Overload					imp imp	
Maximum RMS Overload of Maximum Off State Leaka	current for 1 second ge current I <sub>D</sub> (RMS)		0.1m	50 A	imp imp	⊉ 25°C max.
Maximum RMS Overload of Maximum Off State Leaka	current for 1 second		0.1m	50 A 18 A	imp imp	<b>25°C max</b> .
Maximum RMS Overload of Maximum Off State Leaka Maximum RMS On-State Voltage drop across r	current for 1 second ge current I <sub>p</sub> (RMS) /oltage V <sub>T</sub> (RMS) Maximum elay output @ rated current		0.1m/	50 A 18 A	mp mp 1.0 mA @	25°C max.
Maximum RMS Overload of Maximum Off State Leaka Maximum RMS On-State of Maximu	current for 1 second ge current I <sub>p</sub> (RMS) /oltage V <sub>T</sub> (RMS) Maximum elay output @ rated current		0.1m	50 A 18 A A @ 25°C	mp mp 1.0 mA @	
Maximum RMS Overload of Maximum Off State Leaka Maximum RMS On-State Voltage drop across r	current for 1 second ge current I <sub>D</sub> (RMS) /oltage V <sub>T</sub> (RMS) Maximum elay output @ rated current AACTERISTICS		0.1m	50 A 18 A A @ 25°C	mp mp 1.0 mA @	
Maximum RMS Overload of Maximum Off State Leaka Maximum RMS On-State Voltage drop across of MISCELLANEOUS CHAP	current for 1 second ge current I <sub>D</sub> (RMS) /oltage V <sub>T</sub> (RMS) Maximum elay output @ rated current ACTERISTICS Sec)		0.1m	50 A 18 A A @ 25°C	mp mp 1.0 mA @	
Maximum RMS Overload of Maximum Off State Leaka Maximum RMS On-State Voltage drop across of MISCELLANEOUS CHAPMax. I <sup>2</sup> T for fusing (8.3 m state)	current for 1 second ge current I <sub>D</sub> (RMS) /oltage V <sub>T</sub> (RMS) Maximum elay output @ rated current ACTERISTICS Sec)		0.1m/	50 A 18 A A @ 25°C 1.8V	1.0 mA 6	
Maximum RMS Overload of Maximum Off State Leaka Maximum RMS On-State Voltage drop across of MISCELLANEOUS CHAPMax. I <sup>2</sup> T for fusing (8.3 m statements) Thermal Resistance Junct	current for 1 second ge current I <sub>D</sub> (RMS)  /oltage V <sub>T</sub> (RMS) Maximum elay output @ rated current ACTERISTICS Sec) ion to Case		0.1m	50 A 18 A A @ 25°C 1.8V	Imp Inp 1.0 mA @	
Maximum RMS Overload of Maximum Off State Leaka Maximum RMS On-State of Voltage drop across of MISCELLANEOUS CHAPMAX. IPT for fusing (8.3 m of Thermal Resistance Junct Suggested Heat Sink	current for 1 second ge current I <sub>D</sub> (RMS) /oltage V <sub>T</sub> (RMS) Maximum elay output @ rated current AACTERISTICS Sec) ion to Case		0.1m	50 A 18 A A @ 25°C 1.8V	1.0 mA 6	
Maximum RMS Overload of Maximum Off State Leaka Maximum RMS On-State Voltage drop across of MISCELLANEOUS CHAPMAX. I <sup>2</sup> T for fusing (8.3 m started) Thermal Resistance Junct Suggested Heat Sink Dielectric Strength V <sub>ISO</sub> (Ir	current for 1 second ge current I <sub>D</sub> (RMS) /oltage V <sub>T</sub> (RMS) Maximum elay output @ rated current ACTERISTICS Sec) ion to Case  sput-Output Isolation) @ 500VDC		0.1m	50 A 18 A A @ 25°C 1.8V 3° TO—3 i 2500	1.0 mA 6 1.0 mA 6 24 C/w mounting	
Maximum RMS Overload of Maximum Off State Leakar Maximum RMS On-State of Voltage drop across of MISCELLANEOUS CHAPMAX. IPT for fusing (8.3 m statements) Thermal Resistance Junct Suggested Heat Sink Dielectric Strength V	current for 1 second ge current I <sub>D</sub> (RMS) /oltage V <sub>T</sub> (RMS) Maximum elay output @ rated current ACTERISTICS Sec) ion to Case  uput-Output Isolation) @ 500VDC		0.1m	50 A 18 A A @ 25°C 1.8V 3° TO—3 ( 2500 10	1.0 mA 6 1.0 mA 6 24 26/w mounting 0 VAC	